

Low Noise Amplifier

ZX60-53LN+

 50Ω 0.5 to 5 GHz SMA Female

THE BIG DEAL

- Very wideband, 500 MHz 5 GHz
- Ultra-flat gain, ±0.7 dB from 500 to 2000 MHz
- · Low NF over entire frequency band
- Protected by US patent 6,790,049

Generic photo used for illustration purposes only

Model No.	ZX60-53LN+
Case Style	GC957
Connectors	SMA Female

+RoHS Compliant The +Suffix identifies RoHS Compliance. See our website for methodologies and qualifications

APPLICATIONS

- · Wireless Base Station Systems
- · Test and Measurement Systems
- Multi-Band Receivers

PRODUCT OVERVIEW

Mini-Circuits ZX60-53LN+ is a low-noise amplifier offering industry-leading performance over its full frequency range from 500 MHz to 5 GHz. The internal MMIC amplifier ZX60-53LN+ utilizes E-PHEMT technology to achieve excellent noise figure performance in a unique cascade configuration enabling the combination of very wide band performance and flat gain. This design operates on a single 5V supply and comes in a rugged, compact unobody case (0.74 x 0.75 x 0.46") with SMA connectors, making it an excellent candidate for tough operating conditions and crowded system layouts.

KEY FEATURES

Feature	Advantages					
Ultra-wideband: 500 MHz – 5 GHz	Ideal for a wide range of receiver applications including military, commercial wireless, and instrumentation.					
Very flat gain	Ideal for broadband or multi-band applications. Just one, cost-efficient model required for multiple frequency usage.					
High IP3, +32 dBm typ.	Provides enhanced linearity over broad frequency range.					
High gain, 25 dB typ.	Reduces the number of gain stages, lowering components count and overall! system cost.					
Low operating voltage, +5V	The amplifier features low operating voltage.					
Rugged unibody construction	Mini-Circuits unibody construction integrates the RF connector into the case body, providing high reliability and excellent survivability in critical applications.					

REV. B ECO-015740 ZX60-53LN+ ED-15070802 AG/CP/AM 221107





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ELECTRICAL SPECIFICATIONS AT 25°C, Zo=50Ω AND 5V, UNLESS NOTED OTHERWISE

Parameter	Condition GHz)		V _{DD} =5V		Units	
Faiailletei	Condition di 12)	Min.	Тур.	Max.	Onits	
requency Range		0.5		5	GHz	
	0.5		1.20			
	1.0		1.25			
Noise Figure	2.0		1.45		dB	
Noise Figure	3.0		1.50			
	4.0		1.60			
	5.0		1.90			
	0.5		22.0			
	1.0		22.0			
Set :	2.0	19.5	21.0	23.9	.ID	
Gain	3.0		20.0		dB	
	4.0		19.0			
	5.0		18.0			
Gain Flatness	0.5-2.0		±0.7		dB	
	0.5		16.0			
	1.0		16.5			
	2.0		15.0			
nput Return Loss	3.0		13.0		dB	
	4.0		17.0			
	5.0		14.0			
	0.5		13.0			
	1.0		15.0			
	2.0		20.0			
Output Return Loss	3.0		15.0		dB	
	4.0		15.0			
	5.0		12.0			
	0.5		19.2			
	1.0		19.1			
	2.0		18.9			
Output Power at 1dB Compression ¹	3.0		19.1		dBm	
	4.0		19.5			
	5.0		18.2			
	0.5		32.8			
	1.0		35.0			
_	2.0		31.5			
Output IP3	3.0		31.0		dBm	
	4.0		32.0			
	5.0		30.9			
Active Directivity (Isolation-Gain)	-	_	4.5		dB	
Device Operating Voltage (Vdd)	_	4.9	5.0	7.0	V	
	1		0.0			

Current increases at P1dB.



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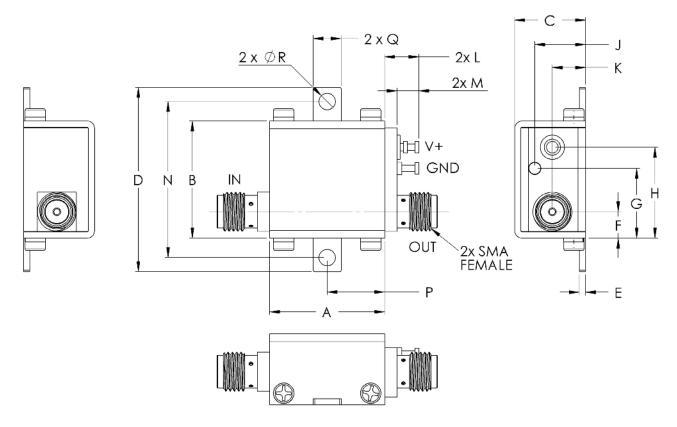
ABSOLUTE MAXIMUM RATINGS²

Parameter	Ratings		
Operating Temperature (ground lead)	-40°C to 85°C		
Storage Temperature	-55°C to 100°C		
Total Power Dissipation	0.7 W		
Input Power	+19 dBm (5 minutes max.) +8 dBm (continuous)		
DC Voltage Vdd	+7V		

^{2.} Permanent damage may occur if any of these limits are exceeded.

Electrical maximum ratings are not intended for continuous normal operation.

OUTLINE DRAWING



NOTE: When soldering the DC connections, caution must be used to avoid overheating the DC terminal. See Application Note. AN-40-010.

OUTLINE DIMENSIONS (Inches)

wt	R	Q	Р	N	M	L	K	J	Н	G	F	Е	D	С	В	Α
grams	.106	.18	.37	1.00	.14	.22	.21	.33	.59	.45	.17	.04	1.18	.46	.75	.74
23.0	2.69	4.57	9.40	25.40	3.56	5.59	5.33	8.38	14.99	11.4	4.32	1.02	30.0	11.68	19.1	18.80



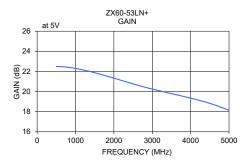
Low Noise Amplifier

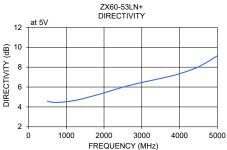
ZX60-53LN+

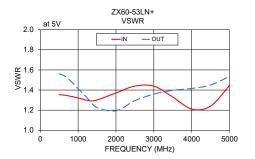
50Ω 0.5 to 5 GHz SMA Female

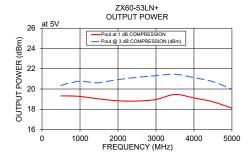
TYPICAL PERFORMANCE DATA/CURVES

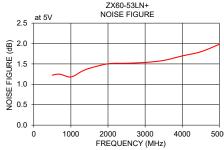
Frequency (MHz)	Gain (dB)	Directivity (dB)	VSVR (:1)		Power Out @1 dB COMPR. (dBm)	Noise Figure (dB)	IP3 (dBm)
			IN	OUT			
500	22.49	4.57	1.35	1.56	19.32	1.23	35.04
700	22.46	4.45	1.35	1.53	19.31	1.25	36.42
1000	22.30	4.52	1.32	1.41	19.27	1.18	36.53
1300	22.06	4.71	1.29	1.30	19.12	1.32	36.03
1500	21.87	4.89	1.30	1.23	19.02	1.39	36.51
2000	21.34	5.41	1.37	1.19	18.84	1.50	34.34
2500	20.76	5.99	1.44	1.30	18.81	1.52	33.34
3000	20.25	6.46	1.44	1.36	18.96	1.54	32.15
3500	19.80	6.86	1.33	1.40	19.46	1.59	32.43
4000	19.35	7.34	1.21	1.42	19.12	1.70	32.88
4500	18.83	8.03	1.24	1.45	18.73	1.80	32.57
5000	18.15	9.14	1.45	1.54	18.11	1.98	32.05

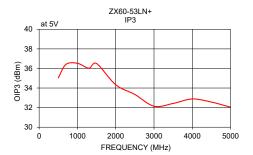












NOTES

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the standard. Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/terms/viewterm.html

